TOSHIBA Photocoupler GaAs IRED & Photo-Transistor

TLP627,TLP627-2,TLP627-4

Programmable Controllers
DC-output Module
Telecommunication

The TOSHIBA TLP627,-2 and -4 consists of a gallium arsenide infrared emitting diode optically coupled to a darlington connected phototransistor which has an integral base-emitter resistor to optimize switching speed and elevated temperature characteristics.

The TLP627-2 offers two isolated channels in a eight lead plastic DIP, while the TLP627-4 provide four isolated channels per package.

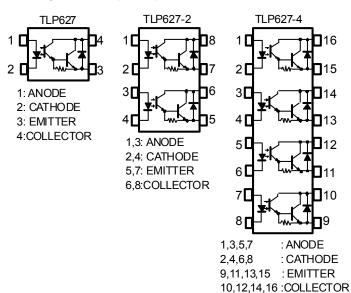
Collector-Emitter Voltage : 300V(Min)
 Current Transfer Ratio : 1000%(Min)
 Isolation Voltage : 5000Vrms(Min)

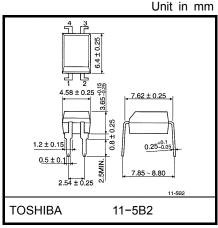
UL Recognized : UL1577, File No. E67349

	Made in Jap	oan	Made in Thailand		
UL Recognized	E67349	*1	E152349	*1	
BSI Approved	7426, 7427	*2	7426, 7427	*2	

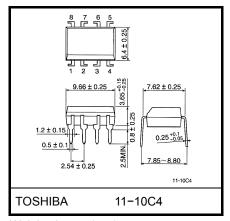
*1 UL1577

Pin Configuration (top view)

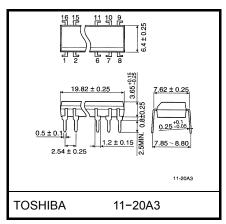




Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

^{*2} BS EN60065: 2002, BS EN60950-1: 2002



Absolute Maximum Ratings (Ta=25°C)

			Ra	Rating		
	Characteristics	Symbol	TLP627 TLP627-2 TLP627-4		Unit	
	Forward Current	I _F	60	50	mA	
	Forward Current Derating	ΔI _F /°C	-0.7(Ta≥39°C)	-0.5(Ta≥25°C)	mA /°C	
	Pulse Forward Current	I _{FP}	1(100µs pu	llse,100pps)	Α	
LED	Power Dissipation (1 Circuit)	P _D	100	70	mW	
	Power Dissipation Derating (Ta≥25°C,1 Circuit)	Δ P _D /°C	-1.0	-0.7	mW /°C	
	Reverse Voltage	V_R		5	V	
	Junction Temperature	Tj	1:	25	°C	
	Collector-Emitter Voltage	V _{CEO}	30	00	V	
	Emitter -Collector Voltage	V _{ECO}	0.3		V	
Detector	Collector Current	Ic	1	50	mA	
Dete	Collector Power Dissipation (1 Circuit)	Pc	150(*300)	100	mW	
	Collector Power Dissipation Derating (Ta≥25°C,1 Circuit)	ΔPc/°C	-1.5(*-3.5)	-1.0	mW /°C	
	Junction Temperature	Tj	1:	25	°C	
Оре	rating Temperature Range	T _{opr}	-55 ⁻	~100	°C	
Stor	age Temperature Range	T _{stg}	-55 ⁻	~125	°C	
Lead	d Soldering Temperature (10s)	T _{sold}	260(1	l0sec)	°C	
Tota	Package Power Dissipation	P _T	250(*320)	250(*320) 150		
Tota	l Package Power Dissipation Derating (Ta≥25°C,1 Circuit)	Δ P _T /°C	-2.5(*-3.2)	-1.5	mW /°C	
Isola	ation Voltage (AC,1min. , R.H.≤60%) (Note1)	BVs	50	000	Vrms	

*IF=20mA Max

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note1)Device considered a two terminal device : LED side pins Shorted together and DETECTOR side pins shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min.	Тур.	Max.	Unit
Supply Voltage	V _{cc}	_	_	200	V
Forward Current	I _F	_	16	25	mA
Collector Current	Ic	_	_	120	mA
Operating Temperature	T _{opr}	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.



Individual Electrical Characteristics (Ta=25°C)

	Characteristics Symbol Test Condition		Min.	Тур.	Max.	Unit	
	Forward Voltage	V _F	V _F		1.15	1.3	V
ED	Reverse Current	I _R	V _R = 5 V	_	_	10	μA
	Capacitance	Ст	V = 0 , f=1MHz	_	30	_	pF
	Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	IC = 0.1mA	300	_	_	V
tor	Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	IE = 0.1mA	0.3	_	_	V
Detector	Collector Dark Current		V _{CE} = 200V	_	10	200	nA
Collector Da	Collector Dark Current	I _{CEO}	V _{CE} = 200V , Ta = 85°C	_	_	20	μA
	Capacitance Collector to Emitter	C _{CE}	V=0 , f=1MHz	_	10	_	pF

Coupled Electrical Characteristics (Ta=25°C)

Characteristics	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Current Transfer Ratio	I _C /I _F	I _F =1mA , V _{CE} =1V	1000	4000	-	%
Saturated CTR	I _C /I _F (sat)	I _F =10mA , V _{CE} =1V	500	_	_	%
Collector-Emitter	V _{CE} (sat)	I _C =10mA , I _F =1mA	_	_	1.0	V
Saturation Voltage		I _C =100mA , I _F =10mA	0.3	_	1.2	V

Isolation Electrical Characteristics (Ta=25°C)

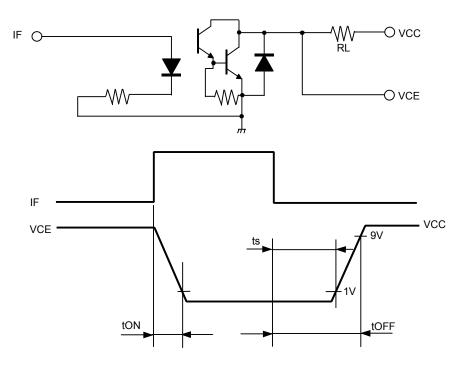
Characteristics	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance Input to Output	Cs	V _S =0 , f=1MHz	_	8.0	_	pF
Isolation Resistance	Rs	V _S =500V , R.H.≤60%	5×10 ¹⁰	10 ¹⁴	1	Ω
Isolation Voltage		AC, 1minute	5000	-	_	Vrms
	BVs	AC, 1second, in oil — 1000	10000	_	VIIIIS	
		DC, 1 minute, in oil	_	10000	_	Vdc

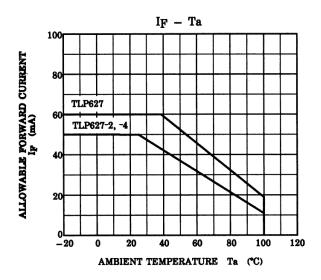


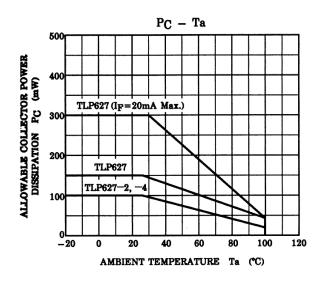
Switching Characteristics (Ta=25°C)

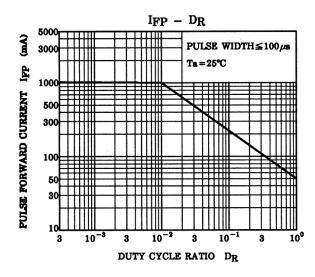
Characteristics	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Rise Time	tr		_	40	_	
Fall Time	tf	V _{CC} =10V	_	15	_	
Turn-on Time	ton	$I_C=10$ mA $R_L=100\Omega$	_	50	_	
Turn-off Time	toff		_	15	_	μs
Turn-on Time	tON	R_L =180 Ω (Fig.1) V_{CC} =10 V , I_F =16 mA	_	5	_	
Strage Time	ts		_	40	_	
Turn-off Time	tOFF		_	80	_	

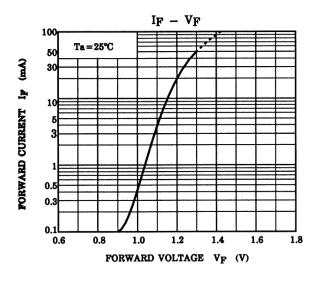
Fig.1 Switching Time Test Circuit

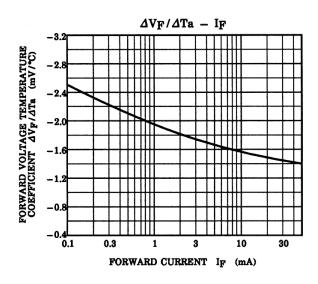


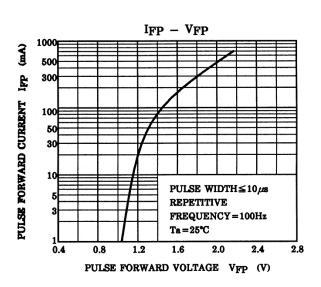


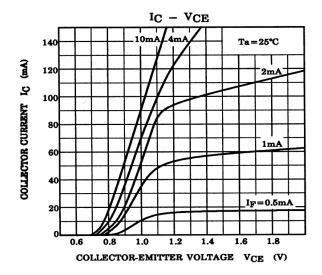


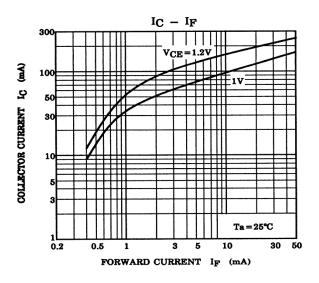


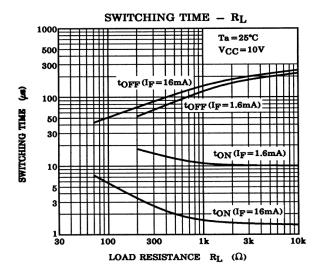


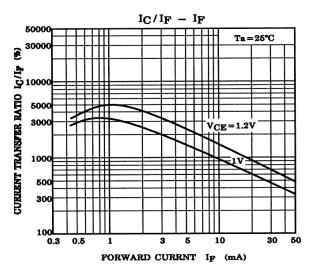


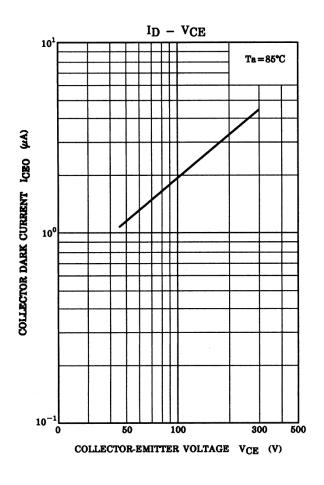


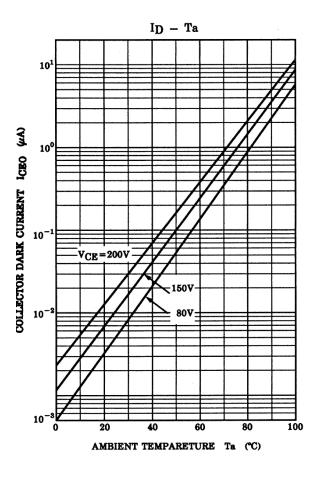


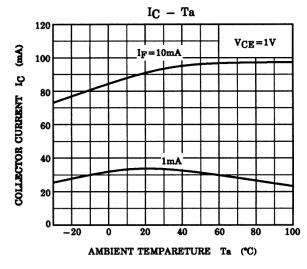


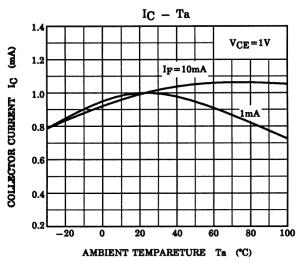














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